BD435G, BD437G, BD439G, BD441G

Plastic Medium-Power Silicon NPN Transistors

This series of plastic, medium–power silicon NPN transistors can be used for amplifier and switching applications.

Features

- Complementary Types are BD438 and BD442
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage BD435G BD437G BD439G BD441G	V _{CEO}	32 45 60 80	Vdc	
Collector–Base Voltage BD435G BD437G BD439G BD441G	V _{CBO}	32 45 60 80	Vdc	
Emitter-Base Voltage	V _{EBO}	5.0	Vdc	
Collector Current	Ι _C	4.0	Adc	
Base Current	Ι _Β	1.0	Adc	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	36 288	W ₩/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

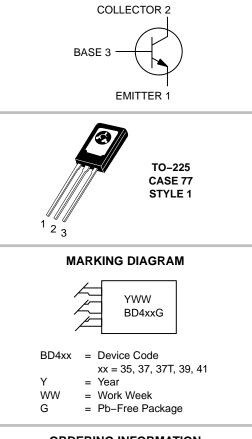
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	R_{\thetaJC}	3.5	°C/W



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4.0 AMPERES POWER TRANSISTORS NPN SILICON



ORDERING INFORMATION

Device	Package	Shipping	
BD435G	TO–225 (Pb–Free)	500 Units/Box	
BD437G	TO–225 (Pb–Free)	500 Units/Box	
BD437TG	TO–225 (Pb–Free)	50 Units/Rail	
BD439G	TO–225 (Pb–Free)	500 Units/Box	
BD441G	TO-225 (Pb-Free)	500 Units/Box	

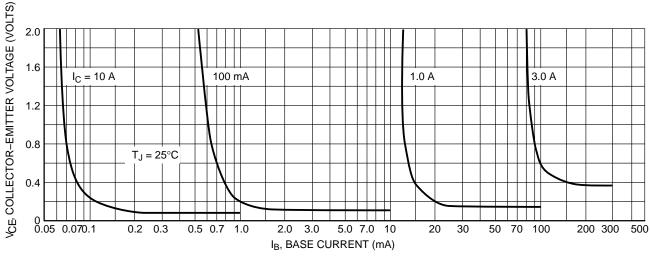
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BD435G, BD437G, BD439G, BD441G

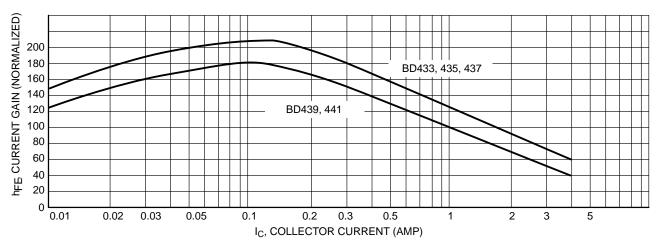
Characteristic	Symbol	Min	Тур	Max	Unit
	V _(BR) CEO	32 45 60 80	- - - -	- - -	Vdc
$\begin{array}{l} \mbox{Collector-Base Breakdown Voltage} \\ (I_{C} = 100 \ \mu\text{A}, \ I_{B} = 0) \\ \mbox{BD435G} \\ \mbox{BD437G} \\ \mbox{BD439G} \\ \mbox{BD441G} \end{array}$	V _(BR) CBO	32 45 60 80	- - - -	- - -	Vdc
Emitter–Base Breakdown Voltage ($I_E = 100 \ \mu A, I_C = 0$)	V _{(BR)EBO}	5.0	-	_	Vdc
Collector Cutoff Current $(V_{CB} = 32 V, I_E = 0)$ BD435G $(V_{CB} = 45 V, I_E = 0)$ BD437G $(V_{CB} = 60 V, I_E = 0)$ BD439G $(V_{CB} = 80 V, I_E = 0)$ BD441G	I _{CBO}	- - -		0.1 0.1 0.1 0.1	mAdc
Emitter Cutoff Current ($V_{EB} = 5.0 V$)	I _{EBO}	_	_	1.0	mAdc
DC Current Gain $(I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V})$ BD435G BD437G BD439G BD439G BD441G	h _{FE}	40 30 20 15		_ _ _ _	-
DC Current Gain (I _C = 500 mA, V _{CE} = 1.0 V) BD435G BD437G BD439G, BD441G	h _{FE}	85 85 40	- - -	475 375 475	-
DC Current Gain (I _C = 2.0 A, V _{CE} = 1.0 V) BD435G BD437G BD439G BD441G	h _{FE}	50 40 25 15	- - - -	- - - -	-
Collector Saturation Voltage $(I_{C} = 2.0 \text{ A}, I_{B} = 0.2 \text{ V})$ BD435G $(I_{C} = 3.0 \text{ A}, I_{B} = 0.3 \text{ A})$ BD437G, BD439G, BD441G	V _{CE(sat)}	-		0.5 0.8	Vdc
Base–Emitter On Voltage (I _C = 2.0 A, V _{CE} = 1.0 V)	V _{BE(on)}	_	_	1.1	Vdc
Current–Gain – Bandwidth Product (V_{CE} = 1.0 V, I _C = 250 mA, f = 1.0 MHz)	f _T	3.0	_	_	MHz

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

BD435G, BD437G, BD439G, BD441G

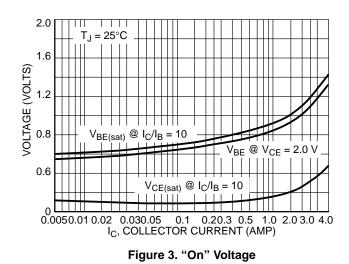








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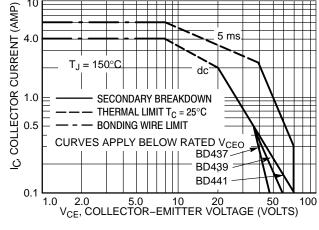
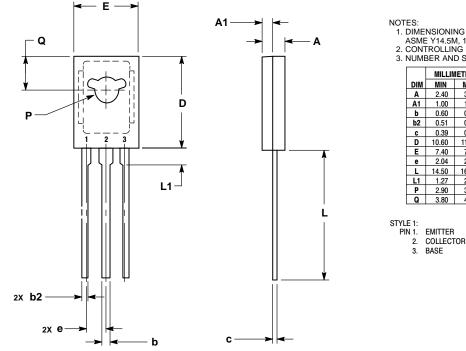


Figure 4. Active Region Safe Operating Area

PACKAGE DIMENSIONS





1. DIMENSIONING AND TOLERANCING PER

ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

MILLIMETERS MIN MAX 2.40 3.00 1.00 1.50 0.60 0.90 0.51 0.88 0.39 0.63 10.60 11.10 7.40 7.80 2.04 2.54 14.50 16.63 1.27 2.54 3.30 2.90 3.80 4.20

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